

June 2011

FPF1203 / FPF1204 IntelliMAX[™] Ultra-Small, Slew-Rate-Controlled Load Switch

Features

- 1.2V to 5.5V Input Voltage Operating Range
- Typical R_{on}:
 - 45mΩ at V_{IN}=5.5V
 - 55mΩ at V_{IN}=3.3V
 - 90mΩ at V_{IN}=1.8V
 - 185mΩ at V_{IN}=1.2V
- Slew Rate Control with t_R: 100µs
- Output Discharge Function on FPF1204
- Low <1.5µA Quiescent Current</p>
- ESD Protected: Above 7kV HBM, 2kV CDM
- GPIO/CMOS-Compatible Enable Circuitry
- 4-Bump, WLCSP 0.76mm x 0.76mm, 0.4mm Pitch

Description

The FPF1203/FPF1204 is ultra-small integrated IntelliMAX[™] load switch with integrated P-channel switch and analog control features. Integrated slew-rate control prevents inrush current and the resulting excessive voltage drop on the power rail. The input voltage range operates from 1.2V to 5.5V to provide power-disconnect capability for post-regulated power rails in portable and consumer products. The low shutoff current of 1µA (maximum) allows power designs to meet standby and off-power drain specifications.

The FPF1203/FPF1204 is controlled by an active-HIGH logic input (ON pin) compatible with standard CMOS GPIO circuitry found on Field Programmable Gate Array (FPGA) embedded processors. The FPF1203/FPF1204 is available in 0.76mm x 0.76mm 4-bump WLCSP.

Applications

- Mobile Devices and Smart Phones
- Portable Media Devices
- Tablet PCs
- Advanced Notebook, UMPC, MID
- Portable Medical Devices
- GPS and Navigation Equipment

Ordering Information

Part Number	Top Mark	Switch (Typical) at 3.3V _{IN}	Output Discharge	ON Pin Activity	t _R	Package
FPF1203UCX	QL	55mΩ	NA	Active HIGH	100µs	4-BUMP, Wafer-Level Chip-Scale
FPF1204UCX	QM	55mΩ	65Ω	Active HIGH	100µs	Package (WLCSP) 0.76mm x 0.76mm, 0.4mm Pitch

Application Diagram

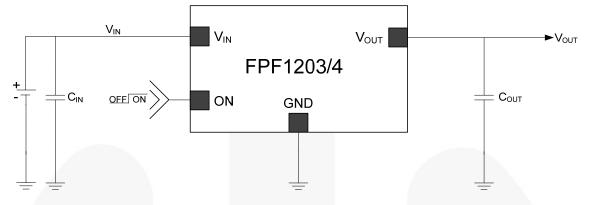


Figure 1. Typical Application

Functional Block Diagram

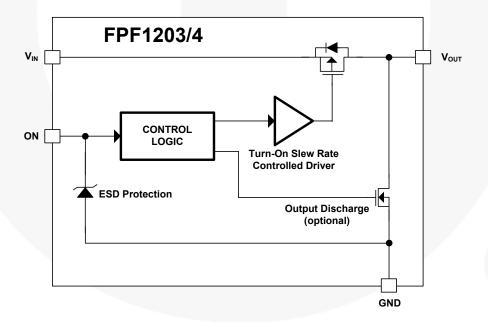


Figure 2. Functional Block Diagram (Output Discharge for FPF1204 Only)

Pin Configurations



Figure 3. WLCSP Bumps Facing Down (Top View)



Figure 4. WLCSP Bumps Facing Up (Bottom View)

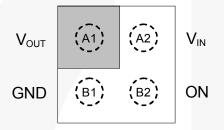


Figure 5. Pin Assignments (Top View)

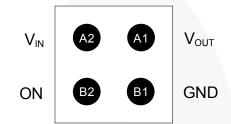


Figure 6. Pin Assignments (Bottom View)

Pin Definitions

Pin#	Name	Description		
A1	V_{OUT}	Switch Output		
A2	V_{IN}	Supply Input: Input to the power switch		
B1	GND	Ground		
B2	ON	ON/OFF Control, active HIGH		

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Paramete	Min.	Max.	Unit	
V _{IN}	V _{IN} , V _{OUT} , V _{ON} to GND		-0.3	6.0	V
I _{SW}	Maximum Continuous Switch Current			1.5	Α
P _D	Power Dissipation at T _A =25°C			1.0	W
T _{STG}	Storage and Operating Temperature Range			+150	°C
0	Thermal Resistance, Junction-to-Ambient	1S2P with One Thermal Via ⁽¹⁾		110 °C/M	
Θ_{JA}	Thermal Resistance, Junction-to-Ambient	1S2P without Thermal Via ⁽²⁾		95	C/VV
ESD	Electrostatic Discharge Capability ^(1,2)	Human Body Model, JESD22-A114	7		- kV
ESD	Liectiostatic Discharge Capability	Charged Device Model, JESD22-C101	2		

Notes:

- Measured using 2S2P JEDEC std. PCB.
- 2. Measured using 2S2P JEDEC PCB COLD PLATE Method.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter		Max.	Unit
V_{IN}	Input Voltage	1.2	5.5	V
T _A	Ambient Operating Temperature		+85	°C

Electrical Characteristics

Unless otherwise noted, V_{IN} =1.2V to 5.5V and T_A =-40 to +85°C. Typical values are at V_{IN} =3.3V and T_A =25°C.

Symbol	Parameter	Parameter Condition		Тур.	Max.	Unit
Basic Oper	ration					
V _{IN}	Supply Voltage		1.2		5.5	V
I _{Q(OFF)}	Off Supply Current	V _{ON} =OFF, V _{OUT} =Open, V _{IN} =5.5V		0.1	1.0	μA
I _{SD}	Shutdown Current	V _{ON} =GND, V _{OUT} =GND			1.0	μA
IQ	Quiescent Current	I _{OUT} =0mA			1.5	μA
		V _{IN} =5.5V, I _{OUT} =200mA, T _A =25°C		45		
		V _{IN} =3.3V, I _{OUT} =200mA, T _A =25°C		55		mΩ
R _{ON}	On Resistance	V _{IN} =1.8V, I _{OUT} =200mA, T _A =25°C		90		
TON	on resistance	V _{IN} =1.2V, I _{OUT} =200mA, T _A =25°C		185		11122
		V _{IN} =1.8V, I _{OUT} =200mA, T _A =85°C ⁽³⁾			105	
R _{PD}	Output Discharge R _{PULL DOWN}	V _{IN} =3.3V, V _{ON} =OFF, I _{FORCE} =20mA, T _A =25°C, FPF1204		65	75	Ω
V _{IH}	On Input Logic HIGH Voltage	V _{IN} =1.2V to 5.5V	1.15			V
	On the state of OWN Vellage	V _{IN} =1.2V to 5.5V			0.65	V
V_{IL}	On Input Logic LOW Voltage	V _{IN} =1.2V to 1.8V			0.60	V
R _{ON_PD}	Pulldown Resistance at ON Pin			8.3		ΜΩ
I _{ON}	On Input Leakage	V _{ON} =V _{IN} or GND			1	μA
Dynamic C	haracteristics					
t _{DON}	Turn-On Delay ⁽⁴⁾			70		
t _R	V _{OUT} Rise Time ⁽⁴⁾	V_{IN} =3.3V, R _L =10 Ω , C _L =0.1 μ F, T _A =25°C		100		μs
t _{ON}	Turn-On Time ⁽⁶⁾	7 7 20 0		170		
t _{DOFF}	Turn-Off Delay ^(4,5)			4.0		
t _F	V _{OUT} Fall Time ^(4,5)	V_{IN} =3.3V, R_L =10 Ω , C_L =0.1 μ F, T_A =25°C, FPF1203		2.9		μs
t _{OFF}	Turn-Off Time ^(5,7)	1,4-23 0,111 1203		7.3		
t _{DOFF}	Turn-Off Delay ^(4,5)			6		
t _F	V _{OUT} Fall Time ^(4,5)	V_{IN} =3.3V, R _L =500 Ω , C _L =0.1 μ F, T _A =25°C, FPF1203		115		μs
t _{OFF}	Turn-Off Time ^(5,7)	1,4-23 0,111 1203		121		
t _{DOFF}	Turn-Off Delay ^(4,5)			4.0		
t _F	V _{OUT} Fall Time ^(4,5)	V_{IN} =3.3V, R_L =10 Ω , C_L =0.1 μ F, T_A =25°C, FPF1204 ⁽⁵⁾		2.5		μs
t _{OFF}	Turn-Off Time ^(5,7)	- IA-23 C, III 1204		6.5		
t _{DOFF}	Turn-Off Delay ^(4,5)			6		
t _F	V _{OUT} Fall Time ^(4,5)	V_{IN} =3.3V, R_L =500 Ω , C_L =0.1 μ F, T_A =25°C, FPF1204 ⁽⁵⁾		11		μs
t _{OFF}	Turn-Off Time ^(5,7)	1 _A -25 C, FFF1204		17		

Notes:

- 3. This parameter is guaranteed by design and characterization; not production tested.
- 4. t_{DON}/t_{DOFF}/t_R/t_F are defined in Figure 22.
- 5. Output discharge enabled during off-state.
- 6. $t_{ON}=t_R + t_{DON}$
- 7. $t_{OFF}=t_F+t_{DOFF}$.

Typical Performance Characteristics

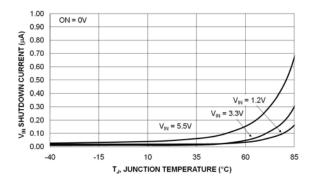


Figure 7. Shutdown Current vs. Temperature

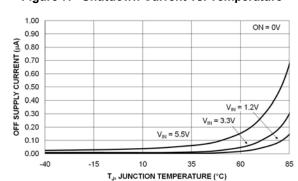


Figure 9. Off Supply Current vs. Temperature (V_{OUT} Floating)

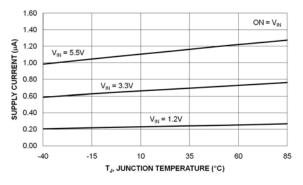


Figure 11. Quiescent Current vs. Temperature

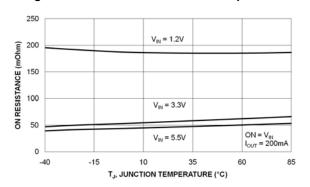


Figure 13. Ron vs. Temperature

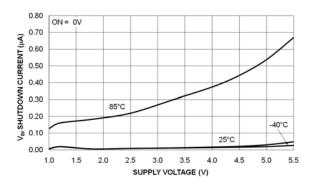


Figure 8. Shutdown Current vs. Supply Voltage

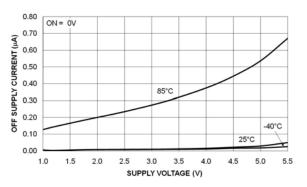


Figure 10. Off Supply Current vs. Supply Voltage (V_{OUT} Floating)

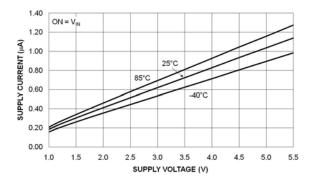


Figure 12. Quiescent Current vs. Supply Voltage

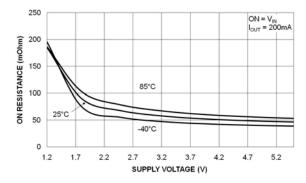
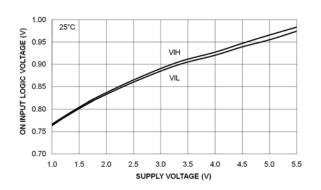


Figure 14. Ron vs. Supply Voltage

Typical Performance Characteristics (Continued)



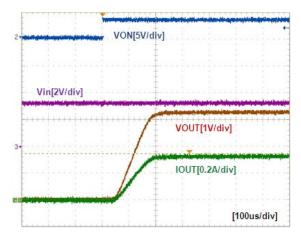
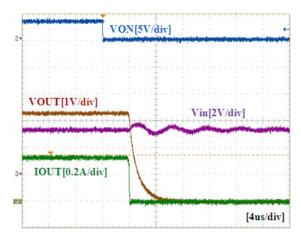


Figure 15. ON Pin Threshold vs. V_{IN}

Figure 16. Turn-On Response (V_{IN}=3.3V, C_{IN}=1 μ F, C_{OUT}=0.1 μ F, R_L=10 Ω)



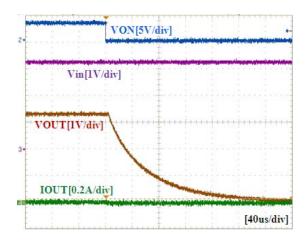
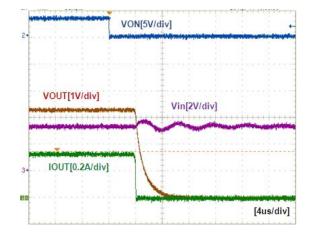


Figure 17. Turn-Off Response (V_{IN} =3.3V, C_{IN} =1 μ F, C_{OUT} =0.1 μ F, R_L =10 Ω , FPF1203)

Figure 18. Turn-Off Response (V_{IN} =3.3V, C_{IN} =1 μ F, C_{OUT} =0.1 μ F, R_L =500 Ω , FPF1203)



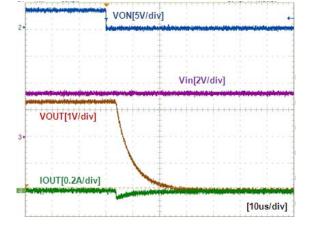


Figure 19. Turn-Off Response (V_{IN}=3.3V, C_{IN}=1 μ F, C_{OUT}=0.1 μ F, R_L=10 Ω , FPF1204)

Figure 20. Turn-Off Response (V_{IN} =3.3V, C_{IN} =1 μ F, C_{OUT} =0.1 μ F, R_L =500 Ω , FPF1204)

Operation and Application Description

The FPF1203/FPF1204 is low-R_{ON} P-channel load switch with controlled turn-on. The core of each device is a $55m\Omega$ P-channel MOSFET and controller capable of functioning over a wide input operating range of 1.2 to 5.5V. The ON pin, an active-HIGH GIOP / CMOScompatible input, controls the state of the switch.

The FPF1204 contains a 65Ω on-chip load resistor for quick output discharge when the switch is turned off.

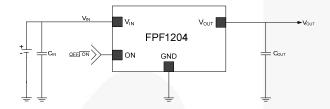


Figure 21. Typical Application

Input Capacitor

To limit the voltage drop on the input supply caused by transient inrush current when the switch turns on into a discharged load capacitor or short-circuit, a capacitor must be placed between the $V_{\rm IN}$ and GND pins. A $1\mu F$ ceramic capacitor, $C_{\rm IN}$, placed close to the pins is usually sufficient. Higher-value $C_{\rm IN}$ can be used to reduce the voltage drop in higher-current applications.

Output Capacitor

A $0.1\mu F$ capacitor, C_{OUT} , should be placed between the V_{OUT} and GND pins. This capacitor prevents parasitic board inductance from forcing V_{OUT} below GND when

the switch is on. C_{IN} greater than C_{OUT} is highly recommended. C_{OUT} greater than C_{IN} can cause V_{OUT} to exceed V_{IN} when the system supply is removed. This could result in current flow through the body diode from V_{OUT} to V_{IN} .

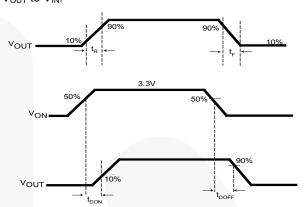
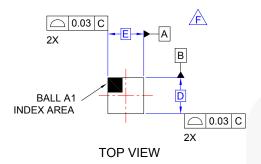


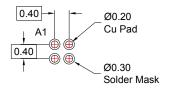
Figure 22. Timing Diagram

Board Layout

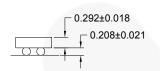
For best performance, traces should be as short as possible. To be most effective, input and output capacitors should be placed close to the device to minimize the effect of parasitic trace inductance on normal and short-circuit operation. Using wide traces or large copper planes for all pins (VIN, VOUT, ON, and GND) minimizes the parasitic electrical effects and the case-ambient thermal impedance. However, the VOUT pin should not connect directly to the battery source due to the discharge mechanism of the load switch.

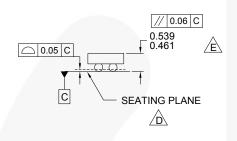
Physical Dimensions





RECOMMENDED LAND PATTERN (NSMD PAD TYPE)





NOTES:

SIDE VIEWS

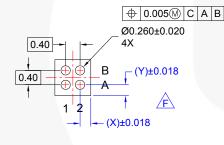
- A. NO JEDEC REGISTRATION APPLIES.
- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS AND TOLERANCE PER ASME Y14.5M, 1994.



E PACKAGE NOMINAL HEIGHT IS 500 MICRONS ±39 MICRONS (461-539 MICRONS).

FOR DIMENSIONS D, E, X, AND Y SEE PRODUCT DATASHEET.

G. DRAWING FILNAME: MKT-UC004AFrev1.



BOTTOM VIEW

Figure 23. 4-Bump, 0.76 x 0.76mm, Wafer-Level Chip-Scale Packaging

Product-Specific Dimensions

Product	D	E	х	Υ
FPF1203UCX	760µm ± 30µm	760µm ± 30µm	0.180mm± 0.018µm	0.180mm± 0.018µm
FPF1204UCX	760μm ± 30μm	760µm ± 30µm	0.180mm± 0.018µm	0.180mm± 0.018µm

Package drawings are provided as a service to customers considering Fairchild components. Drawings may change in any manner without notice. Please note the revision and/or date on the drawing and contact a Fairchild Semiconductor representative to verify or obtain the most recent revision. Package specifications do not expand the terms of Fairchild's worldwide terms and conditions, specifically the warranty therein, which covers Fairchild products.

Always visit Fairchild Semiconductor's online packaging area for the most recent package drawings: http://www.fairchildsemi.com/packaging/.





TRADEMARKS

The following includes registered and unregistered trademarks and service marks, owned by Fairchild Semiconductor and/or its global subsidiaries, and is not intended to be an exhaustive list of all such trademarks.

Intended to be an exhaustive list

AccuPower™

Auto-SPM™

AX-CAP™

BitSiC®

Build it Now™

CorePLUS™

CorePOWER™

CROSSVOLT™

CTL™

Current Transfer Logic™
DEUXPEED®
Dual Cool™
EcoSPARK®
EfficientMax™
ESBC™

Fairchild®
Fairchild Semiconductor®
FACT Quiet Series™
FACT®
FAST®

FAST[®]
FastvCore™
FETBench™
FlashWriter^{®#}

FPSTM
F-PFSTM
FRFET®
Global Power ResourceSM
Green FPSTM
Green FPSTM e-SeriesTM

GTERT POWER STEELS
GTOTM
INTELLIMAXTM
ISOPLANARTM
MEGABUCKTM
MICROCOUPLERTM
MICROFETTM
MicroFettm
MicroPaktm

MicroFetTM
MicroPaktM
MicroPaktM
MicroPaktM
MilerDriveTM
MotionMaxTM
MotionSPMTM
mWSaverTM
OptoHiTTM
OPTOLOGIC®
OPTOPLANAR®

PDP SPM™

Power-SPM™ PowerTrench® PowerXS™

Programmable Active Droop™ QFET®

QFET®
QSTM
Quiet SeriesTM
RapidConfigureTM

SmartMax™

Saving our world, 1mW/W/kW at a time™ SignalWise™

SMART STARTIM SPM®
STEALTHIM SUPERSOTIM-3
SUPERSOTIM-8
SYSTEM-8
SYSTEM-8
SEGENERAL

The Power Franchise®

The Right Technology for Your Success™

Franchies
TinyBoost™
TinyBoost™
TinyCalc™
TinyCalc™
TinyCopro™
TinyPower™
TinyPower™
TinyPwMr™
TinyWire™
TranSic®
TriFault Detect™
TRUECURRENT®**
µSerDes™

SerDes
UHC®
Ultra FRFET™
UniFET™
VCX™
VisualMax™
XS™

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN, NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS:

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used herein:

- Life support devices or systems are devices or systems which, (a)
 are intended for surgical implant into the body or (b) support or
 sustain life, and (c) whose failure to perform when properly used in
 accordance with instructions for use provided in the labeling, can be
 reasonably expected to result in a significant injury of the user.
- A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.fairchildsemi.com, under Sales Support.

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufacturers of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed applications, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handling and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address any warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Recommendation (CAC) (CAC)					
Datasheet Identification	Product Status	Definition			
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.			
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.			
		Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.			
Ob solete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.			

Rev. 154

^{*} Trademarks of System General Corporation, used under license by Fairchild Semiconductor.